Small Outline Optoisolators **Transistor Output**

These devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector, in a surface mountable, small outline, plastic package. They are ideally suited for high density applications, and eliminate the need for through-the-board mounting.

- Convenient Plastic SOIC-8 Surface Mountable Package Style •
- **Closely Matched Current Transfer Ratios** •
- Minimum V(BR)CEO of 70 Volts Guaranteed •
- Standard SOIC–8 Footprint, with 0.050" Lead Spacing
- Shipped in Tape and Reel, which Conforms to EIA Standard RS481A •
- Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering
- High Input–Output Isolation of 3000 Vac (rms) Guaranteed
- UL Recognized **R** File #E54915 ٠

Ordering Information:

- To obtain MOC205, 206, 207, 208 in Tape and Reel, add R2 suffix to device numbers: R2 = 2500 units on 13" reel
- To obtain MOC205, 206, 207, 208 in quantities of 50 (shipped in sleeves) No Suffix

Marking Information:

- MOC205 = 205
- MOC206 = 206
- MOC207 = 207
- MOC208 = 208

Applications:

- Feedback Control Circuits •
- Interfacing and coupling systems of different potentials and impedances
- General Purpose Switching Circuits
- Monitor and Detection Circuits

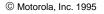
MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

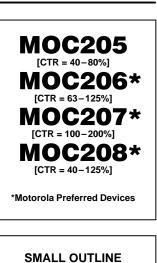
Rating	Symbol	Value	Unit
INPUT LED			
Forward Current — Continuous	١ _F	60	mA
Forward Current — Peak (PW = 100 µs, 120 pps)	I _F (pk)	1.0	А
Reverse Voltage	٧ _R	6.0	V
LED Power Dissipation @ T _A = 25°C Derate above 25°C	PD	90 0.8	mW mW/°C
OUTPUT TRANSISTOR			
Collector–Emitter Voltage	VCEO	70	V
Collector–Base Voltage	VCBO	70	V
Emitter–Collector Voltage	V _{ECO}	7.0	V
Collector Current — Continuous	ΙC	150	mA
Detector Power Dissipation @ T _A = 25°C Derate above 25°C	PD	150 1.76	m₩ mW/°C

NOTE: Thickness through insulation between input and output ≥ 0.5 mm.

Preferred devices are Motorola recommended choices for future use and best overall value

REV 1

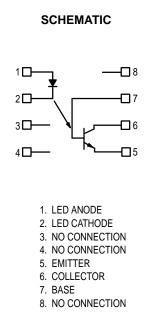




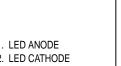


OPTOISOLATORS

TRANSISTOR OUTPUT







MOC205 MOC206 MOC207 MOC208

MAXIMUM RATINGS — continued ($T_A = 25^{\circ}C$ unless otherwise noted)

Rating			Symbol	Va	Value	
OTAL DEVICE				•		
Input–Output Isolation Voltage(1,2) (60 Hz, 1.0 sec. duration)		VISO	3	3000		
Total Device Power Dissipation @ T _A = 25°C Derate above 25°C					250 .94	mW mW/°C
Ambient Operating Temperature Range ⁽³⁾			TA	–55 t	-55 to +100	
Storage Temperature Range ⁽³⁾			T _{stg} -55 to		o +150	°C
Lead Soldering Temperature (1/16" from case, 10 sec. duration)				2	260	°C
ELECTRICAL CHARACTERISTICS	$(T_A = 25^{\circ}C \text{ unless otherwis})$	e noted) ⁽⁴⁾				
Characteristi	C	Symbol	Min	Typ (4)	Max	Unit
NPUT LED			•			•
Forward Voltage (I _F = 10 mA)		VF	-	1.15	1.5	V
Reverse Leakage Current ($V_R = 6.0 V$)		I _R	-	0.1	100	μΑ
Capacitance		С	—	18	—	pF
OUTPUT TRANSISTOR			-			
Collector–Emitter Dark Current (V	CE = 10 V, T _A = 25°C)	ICEO1	—	1.0	50	nA
(\	CE = 10 V, T _A = 100°C)	ICEO2	—	1.0	_	μΑ
Collector–Emitter Breakdown Voltage ($I_C = 100 \ \mu A$)		V(BR)CEO	70	120	_	V
Emitter–Collector Breakdown Voltage ($I_E = 100 \mu A$)		V(BR)ECO	7.0	7.8	—	V
Collector–Emitter Capacitance (f = 1.0 MHz, $V_{CE} = 0$)		C _{CE}	—	7.0	_	pF
OUPLED						
Output Collector Current (I _F = 10 mA, V _{CE} = 10 V)	MOC205 MOC206 MOC207 MOC208	I _C (CTR) ⁽⁵⁾	4.0 (40) 6.3 (63) 10 (100) 4.0 (40)	6.0 (60) 9.4 (94) 15 (150) 8.0 (80)	8.0 (80) 12.5 (125) 20 (200) 12.5 (125)	mA (%)
Collector–Emitter Saturation Voltage (I_C = 2.0 mA, I_F = 10 mA)		V _{CE(sat)}	—	0.15	0.4	V
Turn–On Time (I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω)		ton		3.0	_	μs
Turn–Off Time (I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω)		toff		2.8	_	μs
Rise Time (I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω)		tr		1.6	—	μs
Fall Time (I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω)		tf		2.2	_	μs
Input–Output Isolation Voltage (f = 60 Hz, t = 1.0 sec.)(1,2)		VISO	3000	_	_	Vac(rms
Isolation Resistance $(V_{I-O} = 500 V)^{(2)}$		R _{ISO}	1011	_	_	Ω
Isolation Capacitance ($V_{I-O} = 0$, f = 1.0 MHz) ⁽²⁾		C _{ISO}	-	0.2	-	pF

1. Input–Output Isolation Voltage, $V_{\mbox{\scriptsize ISO}},$ is an internal device dielectric breakdown rating.

2. For this test, pins 1 and 2 are common, and pins 5, 6 and 7 are common.

3. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.

4. Always design to the specified minimum/maximum electrical limits (where applicable).

5. Current Transfer Ratio (CTR) = $I_C/I_F \times 100\%$.

MOC205 MOC206 MOC207 MOC208

TYPICAL CHARACTERISTICS

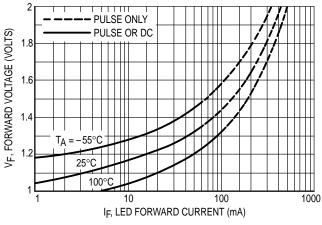


Figure 1. LED Forward Voltage versus Forward Current

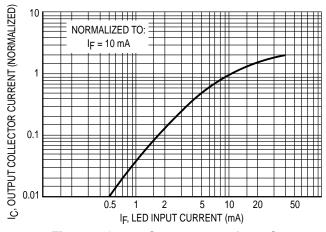
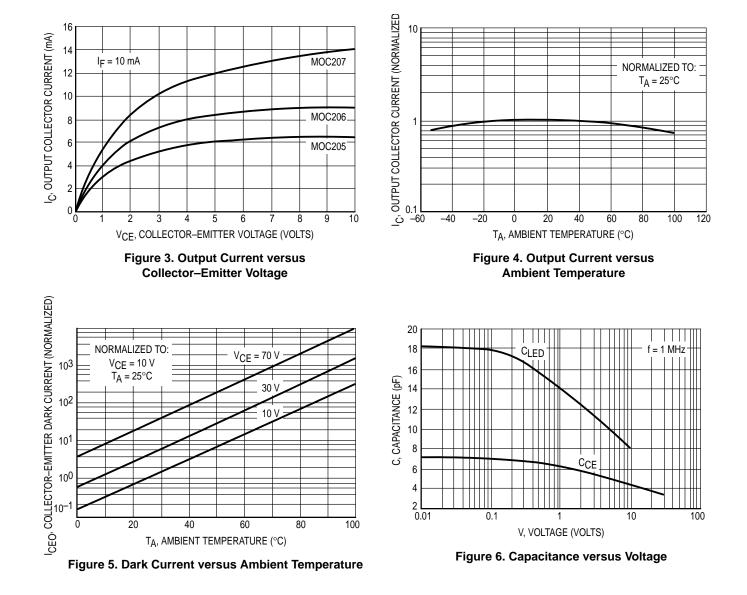


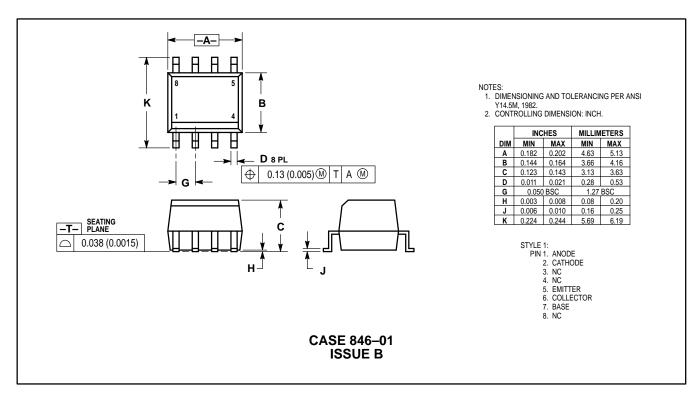
Figure 2. Output Current versus Input Current



Motorola Optoelectronics Device Data

MOC205 MOC206 MOC207 MOC208

PACKAGE DIMENSIONS



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